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Substitute for form 1449A/PTO  <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  <i>(use as many sheets as necessary)</i>			<b>Complete if Known</b>	
	Application Number	161791023		
	Filing Date	3 February 2004 (herewith)		
	First Named Inventor	Hsiang Lan Lung		
	Group Art Unit	2829		
	Examiner Name			
Sheet	1	of	2	Attorney Docket Number
				MXIC 1564-1

U.S. PATENT DOCUMENTS						
Examiner Initials*	Cite No. <sup>1</sup>	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code <sup>2</sup> (if known)			
EJW ↓ V	A1	4,959,812		Momodomi et al.	09-25-1990	
	A2	5,270,969		Iwahashi	12-14-1993	
	A3	5,424,569		Prall	06-13-1995	
	A4	5,448,517		Tanaka	05-07-1996	
	A5	5,644,533		Lancaster et al.	07-01-1997	
	A6	5,768,192		Eitan	06-16-1998	
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	A8	6,172,907		Jenne	01-09-2001	
	A9	6,215,148		Eitan	04-10-2001	
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	A12	Re. 35,838		Momodomi et al.	07-07-1998	
	A13	2002/0179958		Kim	12-05-2002	
	A14					
	A15					
	A16					
	A17					
	A18					
	A19					
	A20					

FOREIGN PATENT DOCUMENTS								
Examiner Initials <sup>1</sup>	Cite No. <sup>1</sup>	Foreign Patent Document			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>6</sup>
		Office <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)				
	B1							
	B2							
	B3							
	B4							
	B5							
	B6							
	B7							
	B8							
	B9							
	B10							

Examiner Signature	/Eric J. Wendler/	Date Considered	02/05/2007
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Substitute for form 1449B/PTO  <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  <i>(use as many sheets as necessary)</i>		<b>Compl to if Known</b>	
		Application Number	10/771,023
		Filing Date	3 February 2004 (herewith)
		First Named Inventor	Hsiang Lan Lung
		Group Art Unit	2824
		Examiner Name	
Sheet	2	of	2
		Attorney Docket Number	MXIC 1564-1

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
EJW	C1	DE BLAUWE, JAN, "Nanocrystal Nonvolatile Memory Devices," IEEE Transactions on Nanotechnology, Vol. 1, No. 1 (March 2002) 72-77	
EJW	C2	LEE, JAE-DUK, "Effects of Floating-Gate Interference on NAND Flash Memory Cell Operation," IEEE Electron Device Letters, Vol. 23, No. 5 (May 2002), 264-266	
EJW	C3	LEE, CHANGHYUN, et al., "A Novel Structure of SiO <sub>2</sub> /SiN/High k Dielectrics, Al <sub>2</sub> O <sub>3</sub> for SONOS Type Flash Memory," Extended Abstracts of the 2002 International Conference on Solid State Device and Materials, Nagoya (2002), 162-163.	
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EJW	C5	LEE, CHANG HYUN, et al., "A Novel SONOS Structure of SiO <sub>2</sub> /SiN/Al <sub>2</sub> O <sub>3</sub> with TaN Metal Gate for Multi-Giga Bit Flash Memories," IEEE (2003) 4 pages.	
EJW	C6	CHUNG, STEVE S., et al., "A Novel Leakage Current Separation Technique in a Direct Tunneling Regime Gate Oxide SONOS Memory Cell," IEEE (2003), 4 pages.	
EJW	C7	HIROSE, M., "Challenges for Future Semiconductor Development," Advance Semiconductor Research Center, National Institute for Advanced Industrial Science and Technology, International Microprocess and Nanotechnology Conference, (6 Nov. 2002), available at <a href="http://www.miraipj.jp/en/opendata/pdf/021106MNC.pdf">http://www.miraipj.jp/en/opendata/pdf/021106MNC.pdf</a> . NO COPY OF DOCUMENT PROVIDED, WEBSITE HAS DOCUMENT LOCKED, CAN ONLY VIEW ON INTERNET	

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				Filing Date	03 February 2004
				First Named Inventor	Hsiang Lan Lung
				Group Art Unit	2824
				Examiner Name	Eric J. Wendler
				Attorney Docket Number	MXIC 1564-1
Sheet	1	of	1		

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